



#### N-CHANNEL ENHANCEMENT MODE MOSFET

## **Product Summary**

V <sub>(BR)DSS</sub>	R <sub>DS(ON)</sub>	I <sub>D</sub> T <sub>A</sub> = +25°C
130V	0.75Ω @ V <sub>GS</sub> = 10V	1.0A
	0.85Ω @ V <sub>GS</sub> = 6.0V	0.9A

### **Description**

This new generation MOSFET has been designed to minimize the on-state resistance ( $R_{DS(ON)}$ ) and yet maintain superior switching performance, making it ideal for high efficiency power management applications.

### **Applications**

- DC-DC Converters
- Power Management Functions
- Battery Operated Systems and Solid-State Relays
- Drivers: Relays, Solenoids, Lamps, Hammers, Displays, Memories, Transistors, etc.

## **Features and Benefits**

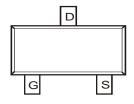
- Low Gate Threshold Voltage
- Low Input Capacitance
- Fast Switching Speed
- Small Surface Mount Package
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)

#### **Mechanical Data**

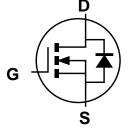
- Case: SOT23
- Case Material: Molded Plastic. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Solderable per MIL-STD-202, Method 208 @3
- Lead Free Plating (Matte Tin Finish Annealed over Alloy 42 Leadframe)
- Terminal Connections: See Diagram
- Weight: 0.006 grams (Approximate)







Top View Pin Configuration



Equivalent Circuit

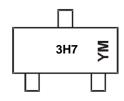
### **Ordering Information** (Note 4)

Part Number	Case	Packaging
DMN13H750S-7	SOT23	3,000/Tape & Reel
DMN13H750S-13	SOT23	10,000/Tape & Reel

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.
- See http://www.diodes.com/quality/lead\_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

## **Marking Information**



3H7 = Product Type Marking Code YM = Date Code Marking Y or  $\overline{Y}$  = Year (ex: C = 2015) M = Month (ex: 9 = September)

### Date Code Key

Year	2014		2015	2016		2017	2018		2019	2020		2021
Code	В		С	D		E	F		G	Н		I
Month	Jan	Feb	Mar	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	0	N	D



### **Maximum Ratings** (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit			
Drain-Source Voltage	Drain-Source Voltage					
Gate-Source Voltage	$V_{GSS}$	±20	V			
Continuous Davis Courset (Note C) V	$T_A = +25^{\circ}C$ $T_A = +70^{\circ}C$	I <sub>D</sub>	1.0 0.8	А		
Continuous Drain Current (Note 6) V <sub>GS</sub> = 10V	t<10s	$T_A = +25$ °C $T_A = +70$ °C	ID	1.2 1.0	А	
Pulsed Drain Current (10µs Pulse, Duty Cycle ≦1%)	I <sub>DM</sub>	3.3	А			
Maximum Body Diode Continuous Current (Note 6)	I <sub>S</sub>	1.2	А			

## Thermal Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic		Symbol	Value	Units
Total Dawer Dissination	(Note 5)	_	0.77	۱۸/
Total Power Dissipation	(Note 6)	$P_D$	1.26	W
Thermal Decistores, Junction to Ambient (Note 5)	Steady state	Б	163	
Thermal Resistance, Junction to Ambient (Note 5)	t<10s	$R_{\theta JA}$	115	
Thermal Decistores, Junction to Ambient (Note 6)	Steady state	Б	99	°C/W
Thermal Resistance, Junction to Ambient (Note 6)	t<10s	$R_{\theta JA}$	70	
Thermal Resistance, Junction to Case	$R_{\theta JC}$	17.3		
Operating and Storage Temperature Range		T <sub>J,</sub> T <sub>STG</sub>	-55 to +150	°C

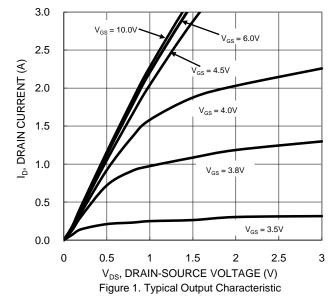
# **Electrical Characteristics** (@T<sub>A</sub> = +25°C, unless otherwise specified.)

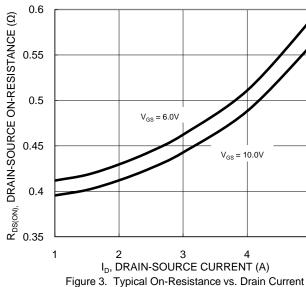
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 7)							
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	130	_	_	>	$V_{GS} = 0V, I_D = 250\mu A$	
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	_	_	100	nΑ	$V_{DS} = 120V, V_{GS} = 0V$	
Gate-Body Leakage	I <sub>GSS</sub>	_	_	±100	nΑ	$V_{GS} = \pm 20V, V_{DS} = 0V$	
ON CHARACTERISTICS (Note 7)							
Gate Threshold Voltage	V <sub>GS(TH)</sub>	2.0	2.7	4.0	>	$V_{DS} = V_{GS}, I_D = 250 \mu A$	
Static Drain-Source On-Resistance	D	_	0.41	0.75	Ω	$V_{GS} = 10V, I_D = 2.0A$	
Static Drain-Source On-Resistance	R <sub>DS (ON)</sub>	_	0.43	0.85	52	$V_{GS} = 6.0V, I_D = 2.0A$	
Diode Forward Voltage	$V_{SD}$	_	0.8	1.2	V	$V_{GS} = 0V, I_{S} = 1.0A$	
DYNAMIC CHARACTERISTICS (Note 8)							
Input Capacitance	Ciss	_	231			$V_{DS} = 25V, V_{GS} = 0V,$ f = 1.0MHz	
Output Capacitance	Coss	_	19		pF		
Reverse Transfer Capacitance	$C_{rss}$	_	11				
Gate Resistance	$R_{G}$	_	2.3	_	Ω	$V_{DS} = 0V$ , $V_{GS} = 0V$ , $f = 1.0MHz$	
Total Gate Charge	Qg	_	5.6	_		10.41/ 1/ 101/	
Gate-Source Charge	$Q_{gs}$		0.8	_	nC	$V_{DS} = 104V, V_{GS} = 10V,$	
Gate-Drain Charge	Q <sub>gd</sub>	_	2.0	_		$I_D = 2.0A$	
Turn-On Delay Time	t <sub>D(ON)</sub>		2.3	_			
Turn-On Rise Time	t <sub>R</sub>	_	1.7	_	20	$V_{DS} = 65V, I_{D} = 2.0A,$	
Turn-Off Delay Time	t <sub>D(OFF)</sub>	_	6.6	_	ns	$V_{GS} = 10V$ , $R_G = 6.0\Omega$	
Turn-Off Fall Time	t <sub>F</sub>		1.7				
Reverse Recovery Time	t <sub>RR</sub>	_	26	_	ns	\/ 100\/	
Reverse Recovery Charge	$Q_{RR}$		21	_	nC	$V_R = 100V$ , $I_F=1.0A$ , $di/dt=100A/\mu s$	

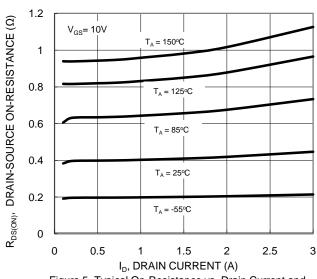
Notes:

- 5. Device mounted on FR-4 PC board, with minimum recommended pad layout, single sided.
  6. Device mounted on FR-4 substrate PC board, 2oz copper, with 1inch square copper pad layout.
  7 .Short duration pulse test used to minimize self-heating effect.
  8. Guaranteed by design. Not subject to production testing.



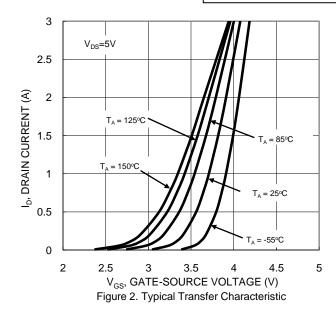


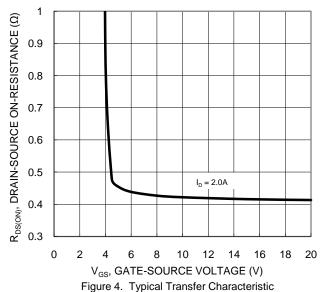




and Gate Voltage

Figure 5. Typical On-Resistance vs. Drain Current and Temperature





2.6

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2.2

2.2

2.8

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Figure 6. On-Resistance Variation with Temperature



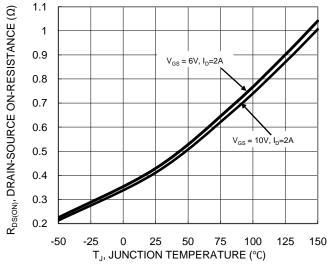


Figure 7. On-Resistance Variation with Temperature

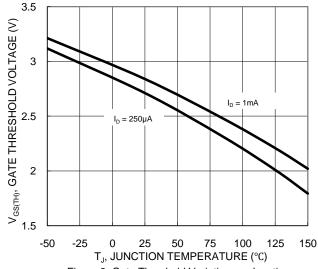


Figure 8. Gate Threshold Variation vs. Junction Temperature

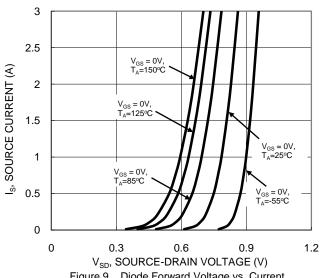
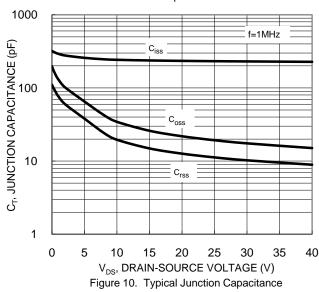
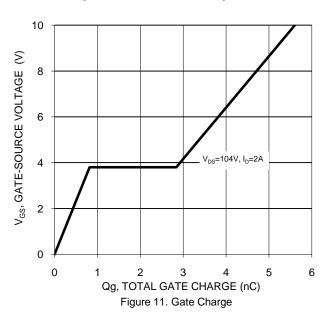
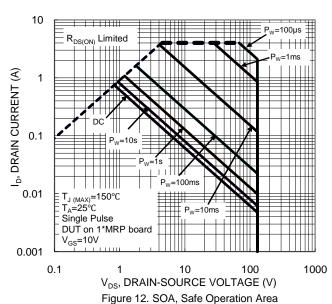


Figure 9. Diode Forward Voltage vs. Current









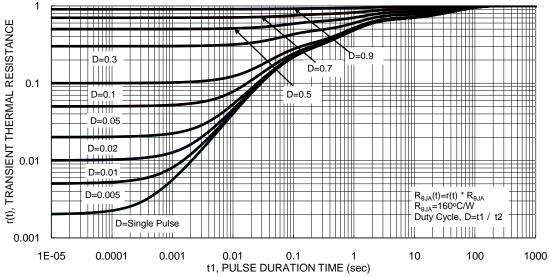
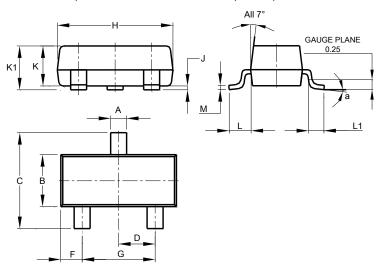


Figure 13. Transient Thermal Resistance

## **Package Outline Dimensions**

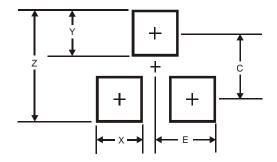
Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for the latest version.



SOT23							
Dim	Min	Max	Тур				
Α	0.37	0.51	0.40				
В	1.20	1.40	1.30				
C	2.30	2.50	2.40				
D	0.89	1.03	0.915				
F	0.45	0.60	0.535				
G	1.78	1.83					
Η	2.80	3.00	2.90				
7	0.013	0.10	0.05				
K	0.890	0.975					
<b>K</b> 1	0.903	1.025					
٦	0.45 0.61 0.5						
L1	0.25 0.55 0.40						
М	0.085 0.150 0.110						
а	8°						
All Dimensions in mm							

# **Suggested Pad Layout**

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.



Dimensions	Value (in mm)				
Z	2.9				
Х	0.8				
Υ	0.9				
С	2.0				
E	1.35				



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